

# RJK4532DPD

450V - 4A - MOS FET  
High Speed Power Switching

R07DS0682EJ0100

Rev.1.00

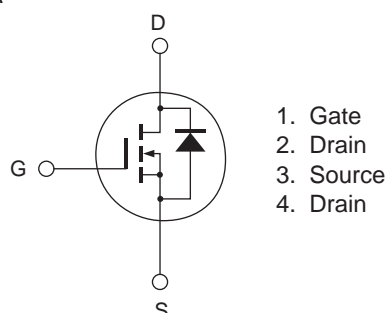
Feb 24, 2012

## Features

- Low on-state resistance  
 $R_{DS(on)} = 1.9 \Omega$  typ. (at  $I_D = 2.0 A$ ,  $V_{GS} = 10 V$ ,  $T_a = 25^\circ C$ )
- Low drive current
- High speed switching

## Outline

RENESAS Package code: PRSS0004ZG-A  
(Package name : MP-3A)



## Absolute Maximum Ratings

( $T_a = 25^\circ C$ )

Item	Symbol	Value	Unit
Drain to source voltage	$V_{DSS}$	450	V
Gate to source voltage	$V_{GSS}$	$\pm 30$	V
Drain current	$I_D$	4	A
Drain peak current	$I_{D(pulse)}$ <sup>Note1</sup>	16	A
Body-drain diode reverse drain current	$I_{DR}$	4	A
Body-drain diode reverse drain peak current	$I_{DR(pulse)}$ <sup>Note1</sup>	16	A
Avalanche current	$I_{AP}$ <sup>Note3</sup>	3	A
Avalanche energy	$E_{AR}$ <sup>Note3</sup>	0.5	mJ
Channel dissipation	$P_{ch}$ <sup>Note 2</sup>	40.3	W
Channel to case thermal Impedance	$\theta_{ch-c}$	3.1	$^\circ C/W$
Channel temperature	$T_{ch}$	150	$^\circ C$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ C$

Notes: 1. Pulse width limited by safe operating area.

2. Value at  $T_c = 25^\circ C$

3.  $ST_{ch} = 25^\circ C$ ,  $T_{ch} \leq 150^\circ C$

## Electrical Characteristics

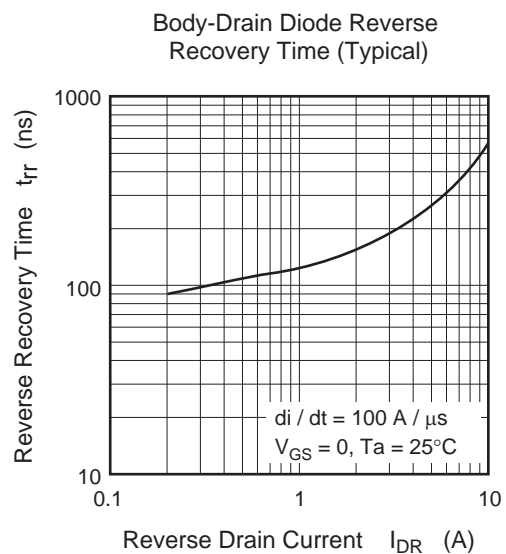
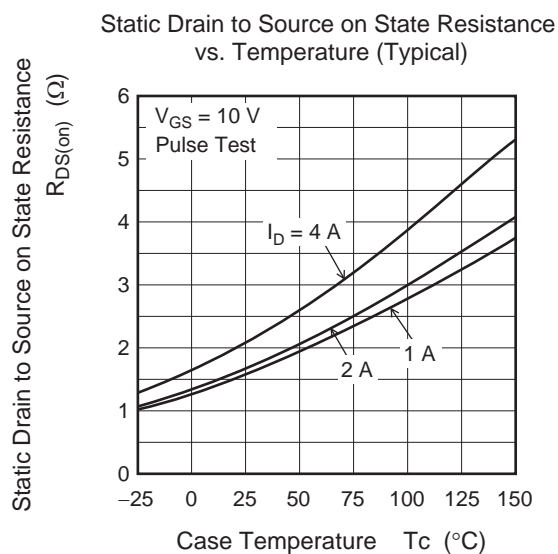
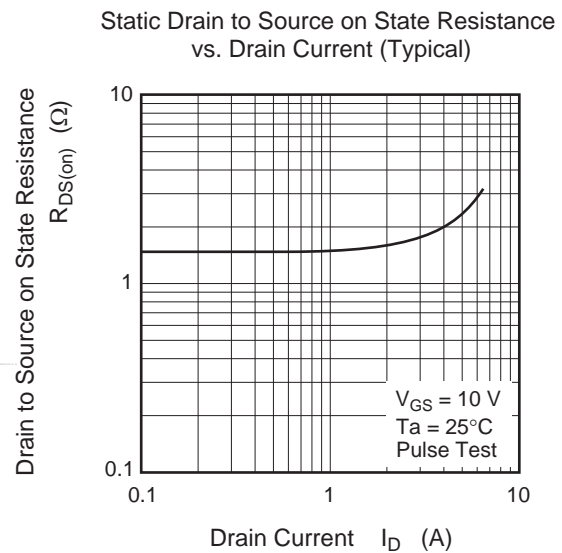
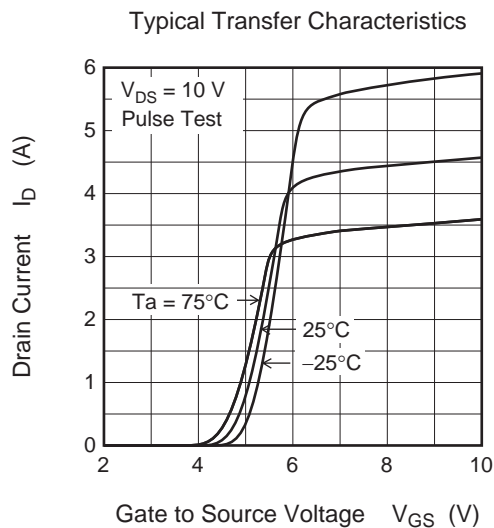
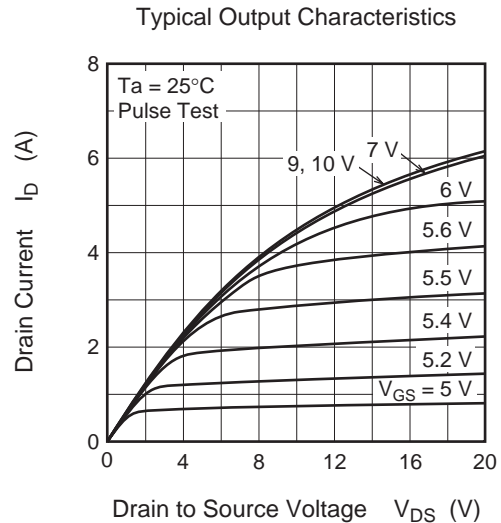
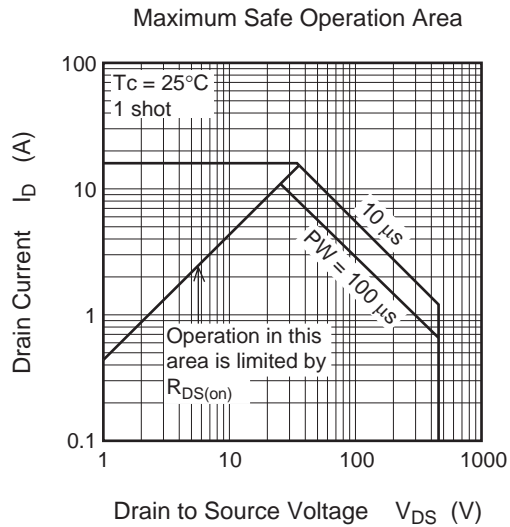
(Ta = 25°C)

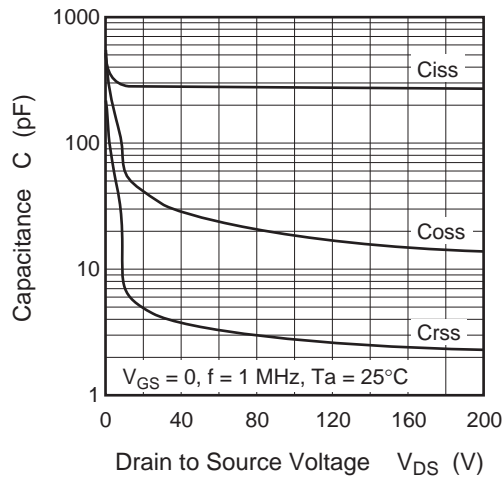
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	450	—	—	V	$I_D = 1 \text{ mA}$ , $V_{GS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	1	$\mu\text{A}$	$V_{DS} = 450 \text{ V}$ , $V_{GS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	$\pm 0.1$	$\mu\text{A}$	$V_{GS} = \pm 30 \text{ V}$ , $V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	3.5	—	4.5	V	$V_{DS} = 10 \text{ V}$ , $I_D = 1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	1.9	2.3	$\Omega$	$I_D = 2 \text{ A}$ , $V_{GS} = 10 \text{ V}$ <sup>Note 4</sup>
Input capacitance	$C_{iss}$	—	280	—	pF	$V_{DS} = 25 \text{ V}$ $V_{GS} = 0$ $f = 1 \text{ MHz}$
Output capacitance	$C_{oss}$	—	36	—	pF	
Reverse transfer capacitance	$C_{rss}$	—	4	—	pF	
Turn-on delay time	$t_{d(on)}$	—	9.0	—	ns	$I_D = 2 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 113 \Omega$ $R_g = 10 \Omega$
Rise time	$t_r$	—	4.5	—	ns	
Turn-off delay time	$t_{d(off)}$	—	20.0	—	ns	
Fall time	$t_f$	—	5.0	—	ns	
Total gate charge	$Q_g$	—	9.0	—	nC	$V_{DD} = 360 \text{ V}$ $V_{GS} = 10 \text{ V}$ $I_D = 4 \text{ A}$
Gate to source charge	$Q_{gs}$	—	2.0	—	nC	
Gate to drain charge	$Q_{gd}$	—	4.5	—	nC	
Body-drain diode forward voltage	$V_{DF}$	—	0.9	1.5	V	$I_F = 4 \text{ A}$ , $V_{GS} = 0$ <sup>Note 4</sup>
Body-drain diode reverse recovery time	$t_{rr}$	—	215	—	ns	$I_F = 4 \text{ A}$ , $V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Note: 4. Pulse test

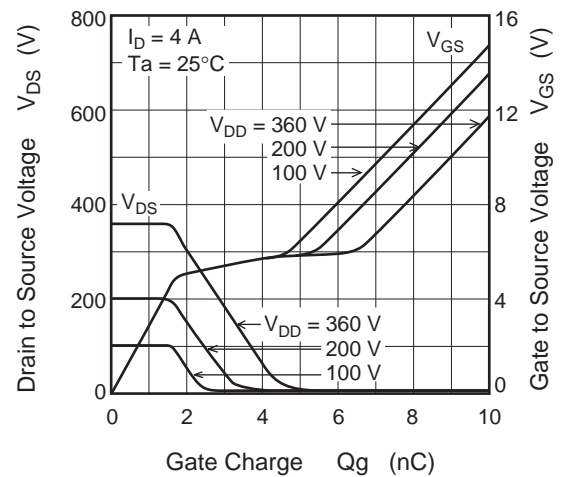
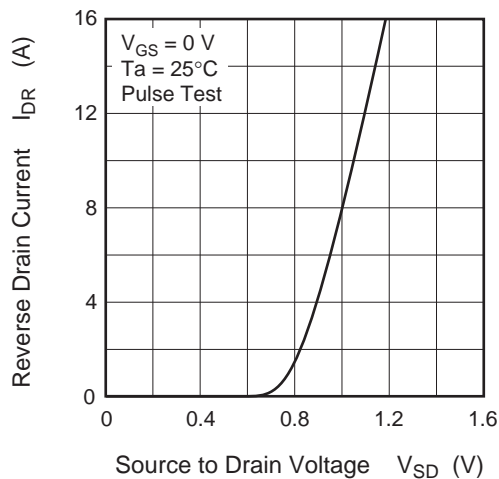
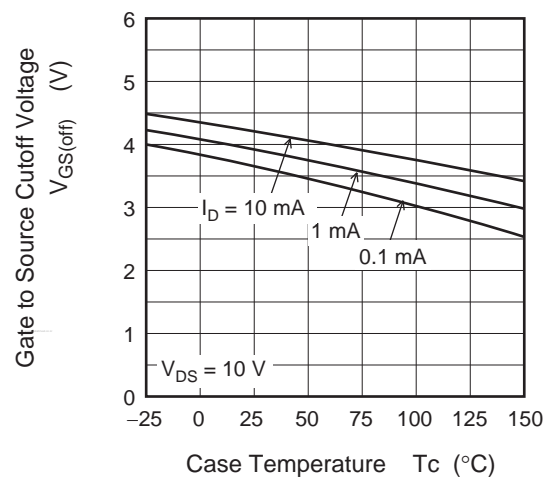
5. Since this device is equipped with high voltage FET chip ( $V_{DSS} \geq 600 \text{ V}$ ), high voltage may be supplied. Therefore, please be sure to confirm about Electric discharge between Drain terminal and other terminal.
6. This device is sensitive to electrostatic discharge.  
It is recommended to adopt appropriate cautions when handling this product.

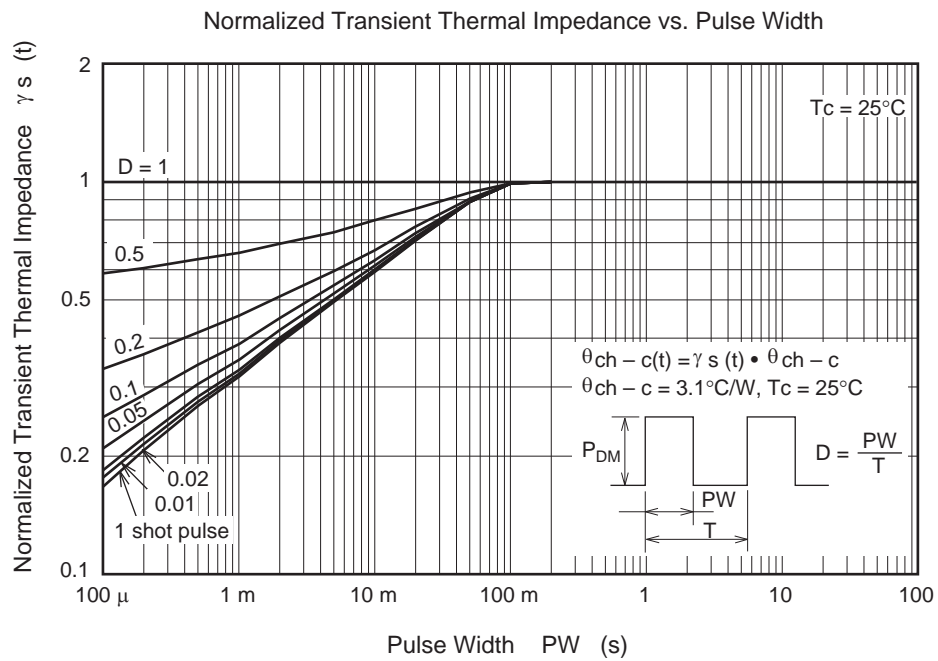
## Main Characteristics



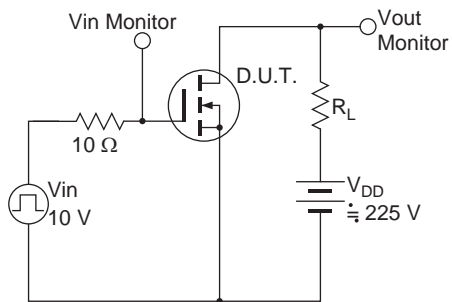
Typical Capacitance vs.  
Drain to Source Voltage

Dynamic Input Characteristics (Typical)

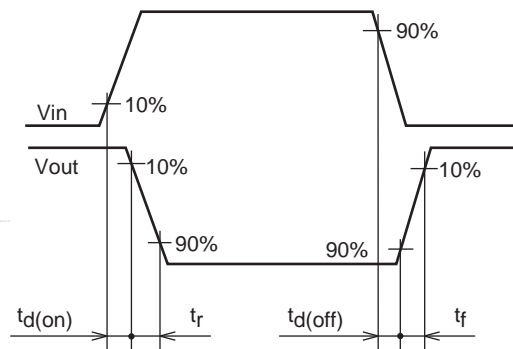
Reverse Drain Current vs.  
Source to Drain Voltage (Typical)Gate to Source Cutoff Voltage  
vs. Case Temperature (Typical)



Switching Time Test Circuit



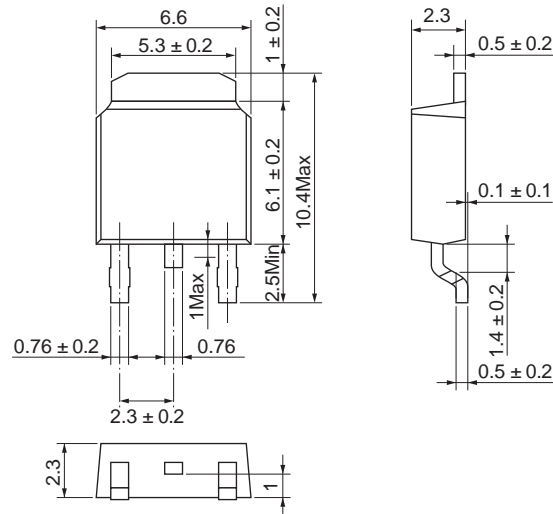
Waveform



## Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
MP-3A	SC-63	PRSS0004ZG-A	TMP3	0.32g

Unit: mm



## Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK4532DPD-00#J2	3000 pcs	Taping

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